

**MCT2200X, MCT2201X, MCT2202X,
MCT2200, MCT2201, MCT2202**



**OPTICALLY COUPLED
ISOLATOR
PHOTOTRANSISTOR OUTPUT**

APPROVALS

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
 - VDE 0884 in 3 available lead forms :-
 - STD
 - G form
 - SMD approved to CECC 00802
 - Certified to EN60950 by the following Test Bodies :-
 - Nemko - Certificate No. P96101299
 - Fimko - Registration No. 190469-01..22
 - Semko - Reference No. 9620076 01
 - Demko - Reference No. 305567

DESCRIPTION

The MCT220_ series of optically coupled isolators consist of an infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

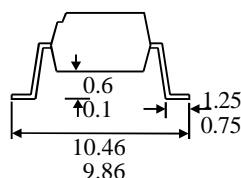
FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- All electrical parameters 100% tested
- Custom electrical selections available

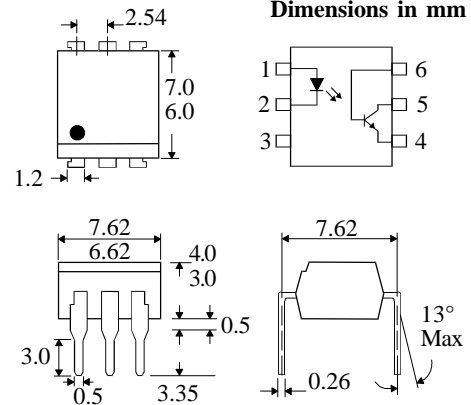
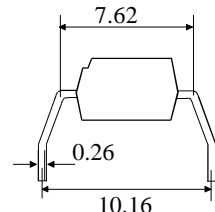
APPLICATIONS

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

**OPTION SM
SURFACE MOUNT**



OPTION G



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature _____ -55°C to + 150°C
 Operating Temperature _____ -55°C to + 100°C
 Lead Soldering Temperature
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 60mA
 Reverse Voltage _____ 6V
 Power Dissipation _____ 105mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 30V
 Collector-base Voltage BV_{CBO} _____ 70V
 Emitter-base Voltage BV_{EBO} _____ 5V
 Power Dissipation _____ 160mW

POWER DISSIPATION

Total Power Dissipation _____ 200mW
 (derate linearly 2.67mW/°C above 25°C)

ISOCOM COMPONENTS LTD

Unit 25B, Park View Road West,
 Park View Industrial Estate, Brenda Road
 Hartlepool, Cleveland, TS25 1YD
 Tel: (01429) 863609 Fax :(01429) 863581

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION	
Input	Forward Voltage (V_F)		1.2	1.5	V	$I_F = 20\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 3\text{V}$	
	Reverse Voltage (V_R)	3			V		
	Reverse Current (I_R)			10	μA		
Output	Collector-emitter Breakdown (BV_{CEO}) (note 2)	30			V	$I_C = 1\text{mA}$ $I_C = 100\mu\text{A}$ $I_E = 100\mu\text{A}$ $V_{CE} = 10\text{V}$	
	Collector-base Breakdown (BV_{CBO})	70			V		
	Emitter-base Breakdown (BV_{EBO})	5			V		
	Collector-emitter Dark Current (I_{CEO})			50	nA		
Coupled	Current Transfer Ratio (CTR)					$10\text{mA } I_F, 5\text{V } V_{CE}$	
	MCT2200	20			%		
	MCT2201	100			%		
		MCT2202	63		125	%	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.4		V	$10\text{mA } I_F, 2.5\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300				V_{RMS}	See note 1
		7500				V_{PK}	See note 1
Input-output Isolation Resistance R_{ISO}	5×10^{10}				Ω	$V_{IO} = 500\text{V}$ (note 1)	
Turn-on Time t_{ON}			10		μs	$V_{CC} = 5\text{V}, R_L = 100\Omega,$ $I_C = 2\text{mA}$, (fig 1)	
Turn-off Time t_{OFF}			10		μs		

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

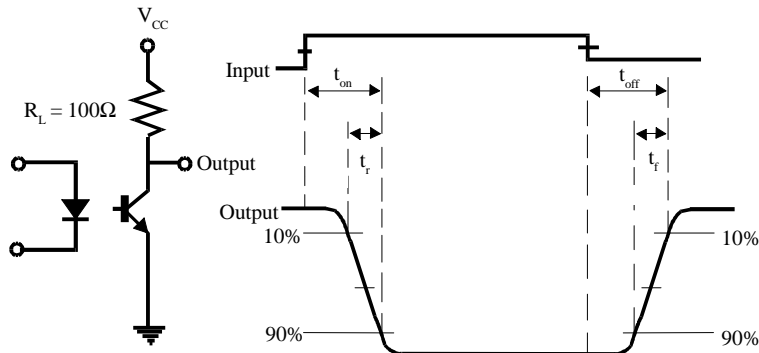
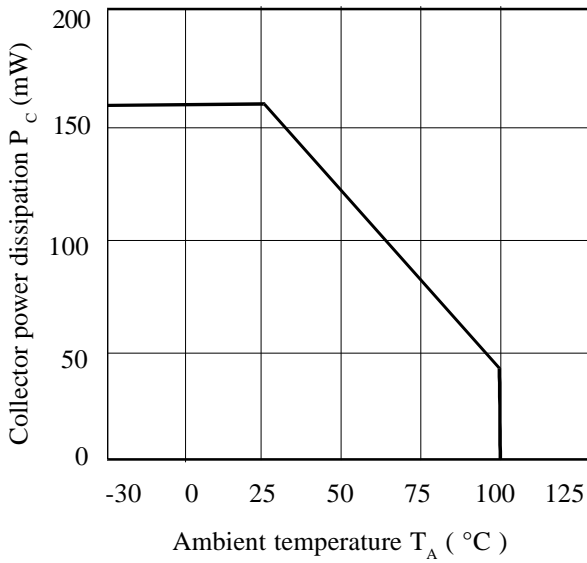
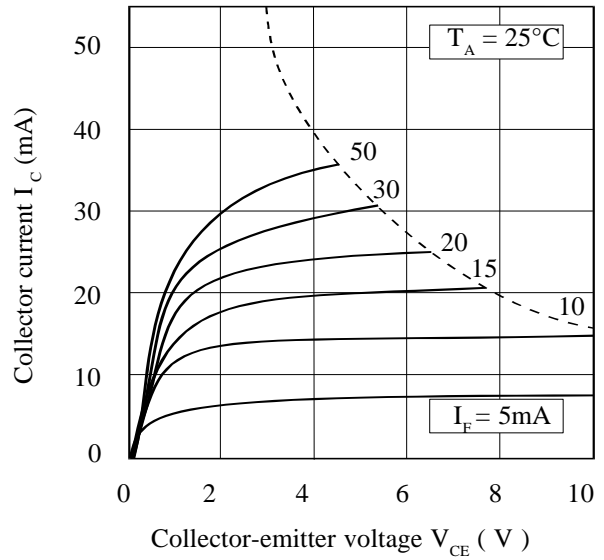


FIG 1

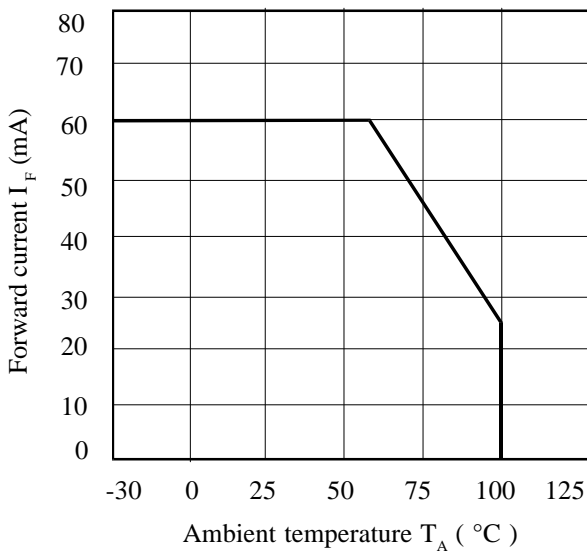
Collector Power Dissipation vs. Ambient Temperature



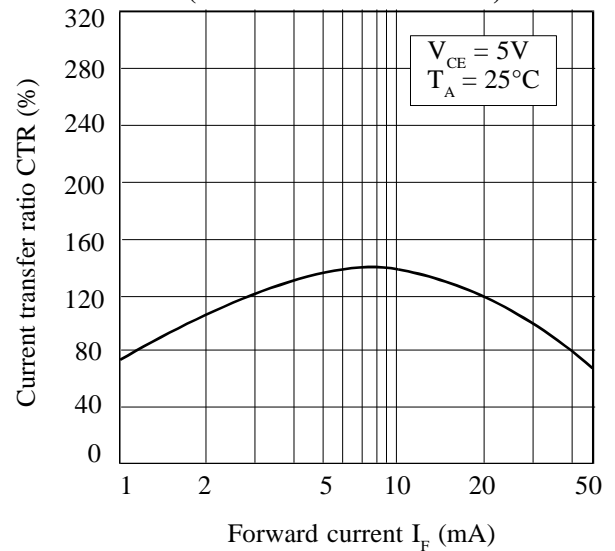
Collector Current vs. Collector-emitter Voltage (normalised to MCT2201)



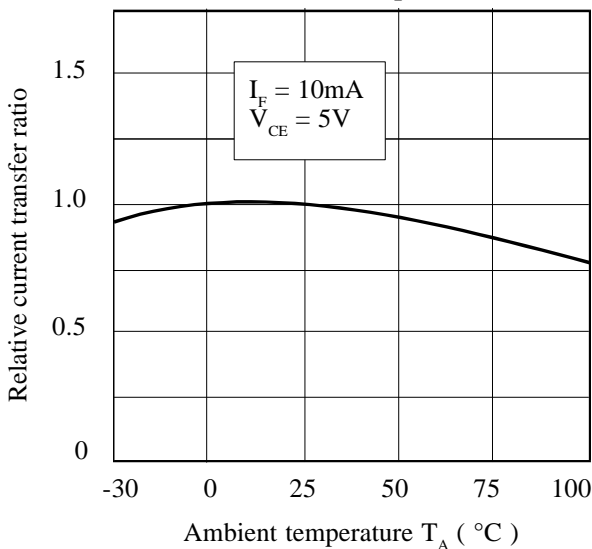
Forward Current vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current (normalised to MCT2201)



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature

